

DESCRIPTION

The IS124 consists of an infrared light emitting diode optically coupled to an NPN silicon photo transistor in a space efficient Mini Flat Package.

FEATURES

- Low Profile Package
- AC Isolation Voltage 3750V_{RMS}
- CTR Typical 100% at I_F 0.5mA V_{CE} 1.5V
- Wide Operating Temperature Range -55°C to +110°C
- Lead Free and RoHS Compliant
- UL File E91231 model "FPT2"

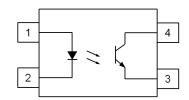
APPLICATIONS

- **Computer Terminals**
- **Industrial System Controllers**
- Measuring Instruments
- Signal Transmission between Systems of Different Potentials and Impedance

ORDER INFORMATION

Available in Tape and Reel with 3000 pieces per reel





- Anode
- 2 Cathode
- Emitter
- Collector

ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Stresses exceeding the absolute maximum ratings can cause permanent damage to the device.

Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

Input

Forward Current	50mA
Peak Forward Current (100µs, 100Hz)	1A
Reverse Voltage	6V
Power Dissipation	70mW
Junction Temperature	125°C

Output

Collector to Emitter Voltage V _{CEO}	80V
Emitter to Collector Voltage V _{ECO}	6V
Collector Current	50mA
Power Dissipation	150mW
Junction Temperature	125°C

Total Package

Isolation Voltage	$3750V_{RMS}$
Total Power Dissipation	170mW
Operating Temperature	-55 to +110°C
Storage Temperature	-55 to +150°C

Lead Soldering Temperature (10s) 260°C

ISOCOM COMPONENTS 2004 LTD

Unit 25B, Park View Road West, Park View Industrial Estate Hartlepool, Cleveland, TS25 1PE, United Kingdom Tel: +44 (0)1429 863 609 Fax: +44 (0)1429 863 581 e-mail: sales@isocom.co.uk http://www.isocom.com

ISOCOM COMPONENTS ASIA LTD

Hong Kong Office
Block A, 8/F, Wah Hing Industrial Mansions
36 Tai Yau Street, San Po Kong, Kowloon, Hong Kong
Tel: +852 2995 9217 Fax: +852 8161 6292
e-mail: sales@isocom.com.hk



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

INPUT

Parameter	Symbol	ol Test Condition		Тур.	Max	Unit
Forward Voltage	V_{F}	$I_F = 20 \text{mA}$		1.2	1.4	V
Reverse Current	I_R	$V_R = 4V$			10	μΑ
Terminal Capacitance	C_{t}	V = 0V, $f = 1KHz$		30	250	pF

OUTPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector-Emitter Breakdown Voltage	$\mathrm{BV}_{\mathrm{CEO}}$	$I_C = 0.1 \text{mA}, I_F = 0 \text{ mA}$	80			V
Emitter-Collector Breakdown Voltage	$\mathrm{BV}_{\mathrm{ECO}}$	$I_E = 10\mu A,I_F = 0mA$	6			V
Collector-Emitter Dark Current	I_{CEO}	$V_{CE} = 20V$, $I_F = 0mA$			100	nA

COUPLED

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Current Transfer Ratio	CTR	$I_F = 5mA$, $V_{CE} = 5V$	50		600	%
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_F = 20 \text{mA}, I_C = 1 \text{mA}$			0.2	V
Floating Capacitance	C_{f}	V = 0V, $f = 1MHz$		0.6	1	pF
Output Rise Time	$t_{\rm r}$	$V_{CE} = 2V$ $Ic = 2mA$		4	18	μs
Output Fall Time	t_{f}	$R_{L} = 100\Omega$		3	18	μs

ISOLATION

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Isolation Voltage	$V_{\rm ISO}$	RH = 40% to 60%, $t = 1 min$	3750			V_{RMS}
Input - Output Resistance	R _{I-O}	RH = 40% to 60% $V_{I-O} = 500 VDC$	5x10 ¹⁰	1x10 ¹¹		Ω

Measured with input leads shorted together and output leads shorted together.



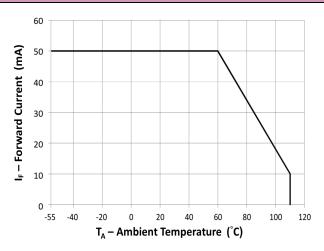


Fig 1 Forward Current vs Ambient Temperature

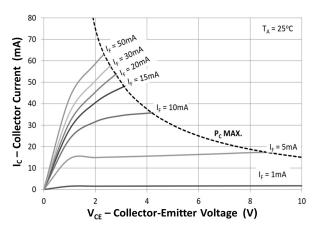


Fig 3 Collector Current vs Collector-Emitter Voltage

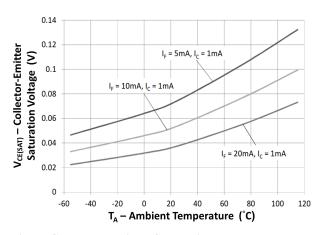


Fig 5 Collector-Emitter Saturation Voltage vs Ambient Temperature

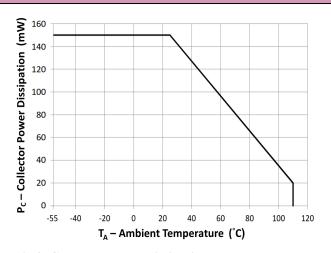


Fig 2 Collector Power Dissipation vs Ambient Temperature

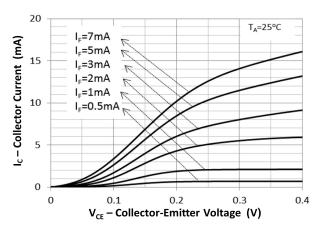


Fig 4 Collector Current vs Collector-Emitter Saturation Voltage

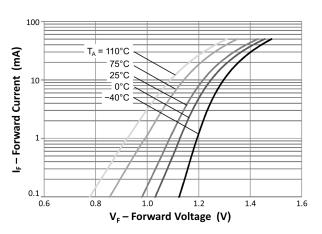


Fig 6 Forward Current vs Forward Voltage



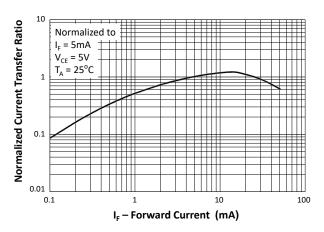


Fig 7 Normalized Current Transfer Ratio vs Forward Current

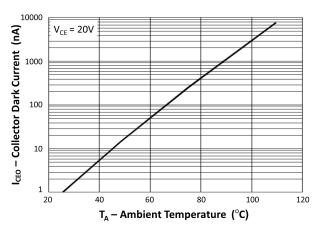


Fig 9 Collector Dark Current vs Ambient Temperature

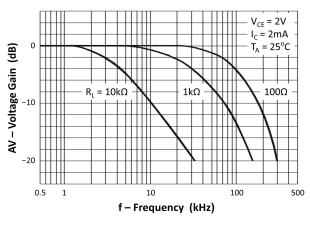


Fig 11 Frequency Response

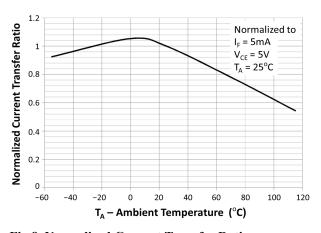


Fig 8 Normalized Current Transfer Ratio vs Ambient Temperature

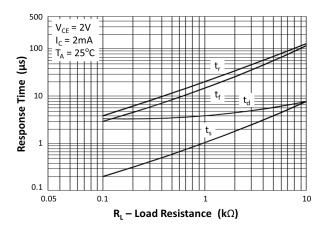
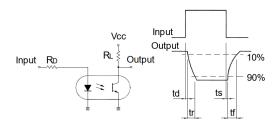
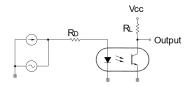


Fig 10 Response Time vs Load Resistance



Response Time Test Circuit



Frequency Response Test Circuit



ORDER INFORMATION

IS124			
After PN	PN	Description	Packing quantity
None	IS124	Surface Mount Tape & Reel	3000 pcs per reel

DEVICE MARKING



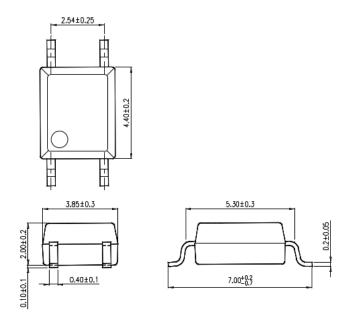
FPT2 denotes Device Part Number

I denotes Isocom

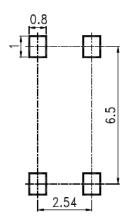
Y denotes 1 digit Year code WW denotes 2 digit Week code



PACKAGE DIMENSIONS (mm)

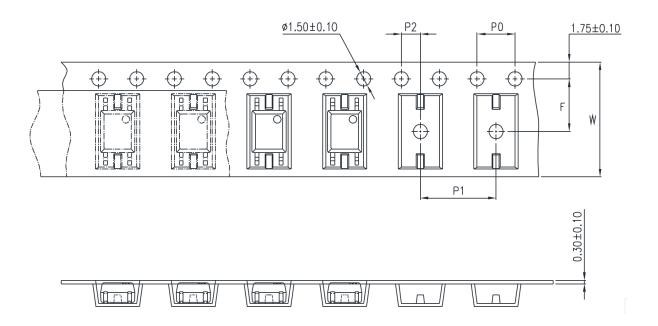


RECOMMENDED SOLDER PAD LAYOUT (mm)





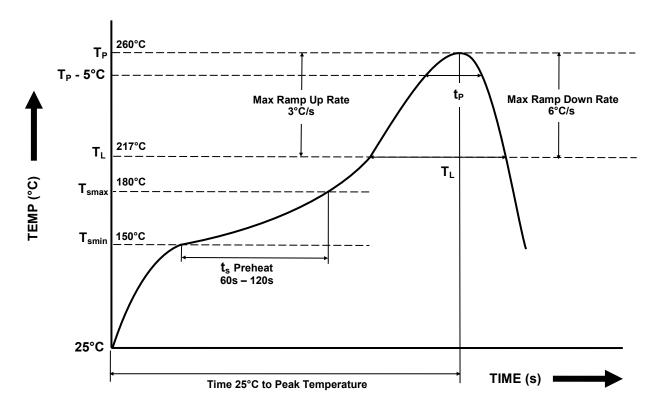
TAPE AND REEL PACKAGING



Description	Symbol	Dimension mm (inch)
Tape Width	W	12 ± 0.3 (0.47)
Pitch of Sprocket Holes	P ₀	4 ± 0.1 (0.15)
Distance of Compartment to Sprocket Holes	F	5.5 ± 0.1 (0.217)
Distance of Compartment to Sprocket Holes	P ₂	2 ± 0.1 (0.079)
Distance of Compartment to Compartment	P ₁	8 ± 0.1 (0.315)



IR REFLOW SOLDERING TEMPERATURE PROFILE One Time Reflow Soldering is Recommended. Do not immerse device body in solder paste.



Profile Details	Conditions
Preheat - Min Temperature (T _{SMIN}) - Max Temperature (T _{SMAX}) - Time T _{SMIN} to T _{SMAX} (t _s)	150°C 180°C 60s - 120s
$\begin{tabular}{lll} \textbf{Soldering Zone} \\ - & \text{Peak Temperature } (T_P) \\ - & \text{Liquidous Temperature } (T_L) \\ - & \text{Time within } 5^\circ C \text{ of Actual Peak Temperature } (T_P - 5^\circ C) \\ - & \text{Time maintained above } T_L \ (t_L) \\ - & \text{Ramp Up Rate } (T_L \ to \ T_P) \\ - & \text{Ramp Down Rate } (T_P \ to \ T_L) \\ \end{tabular}$	260°C 217°C 20s 60s 3°C/s max 3 - 6°C/s
Average Ramp Up Rate (T _{smax} to T _P)	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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